

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Fwu-Iuan Hshieh et al.  
Application No.: Unassigned  
Date Filed: Filed Herewith  
Title: HIGH SPEED TRENCH DMOS  
Group Art: 2818  
Examiner: Unassigned  
Docket: D2337 D2

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INFORMATION DISCLOSURE STATEMENT (IDS)

Mail Stop Patent  
Commissioner For Patents  
P.O. Box 1450  
Alexandria, VA 22231-1450

SIR:

In accordance with 37 C.F.R. §1.56 and in compliance with 37 C.F.R. §§1.97 and 1.98, the references listed on attached Form PTO/SB/08 and/or subsequently identified herein, are being submitted herewith for consideration by the United States Patent and Trademark Office.

I. COPIES

a.  A legible copy of (i) each U.S. and foreign patents; (ii) each publication or that portion which caused it to be listed; and (iii) all other information or that portion which caused it to be listed, is included herewith.

b.  Any patents, publications or other information which are listed on PTO/SB/08 which are not enclosed herewith were previously cited by or submitted to the PTO in one of the following applications which has been relied upon for an earlier filing date under 35 U.S.C. §120:

U.S. Serial Number  
09/515,749  
09/882,117

U.S. Filing Date  
February 29, 2000  
June 15, 2001

II. CONCISE EXPLANATION OF THE RELEVANCE (check at least one box)

a.  Except as may be indicated below in (b) of this section, all of the patents, publications or other information are in the English language (concise explanation not required).

b.  A concise explanation of the relevance of all patents, publications or other information listed that is not in the English language is as follows:

c.  The following additional information is provided for the Examiner's consideration:

III.  CROSS REFERENCE TO RELATED APPLICATION(S)

The Examiner is advised that the following co-pending application(s) contain(s) subject matter that may be related to the present application. By bringing this (these) applications to the Examiner's attention, Applicant(s) does(do) not waive the confidentiality provisions of 35 U.S.C. §122.

Serial No.

Filing Date

Art Unit

**FEES**

IV.  **THIS IDS IS BEING FILED UNDER 37 C.F.R. §1.97(b):** (check one box)

a.  within three months of the filing date of a national application other than a continued prosecution application under § 1.53(d) (37 C.F.R. §1.97(b)(1)). No fee or statement is required.

b.  within three months of the date of entry of the national stage as set forth in § 1.491 in an international application (37 C.F.R. §1.97(b)(2)). No fee or statement is required.

c.  before the mailing date of a first Office Action on the merits (37 C.F.R. §1.97(b)(3)). No fee or statement is required.

d.  before the mailing date of a first Office Action after the filing of a request for continued examination under § 1.114 (37 C.F.R. § 1.97(b)(4)). No fee or statement is required.

V.  **THIS IDS IS BEING FILED UNDER 37 C.F.R. §1.97(c):** (check one box)

before the mailing date of any of a Final Office Action under 37 C.F.R. §1.113, a Notice of Allowance under 37 C.F.R. §1.311, or an action that otherwise closes prosecution in the application (See 37 C.F.R. §1.97(c)).

a.  No statement; therefore, charge deposit account 50-1047 the fee set forth in 37 C.F.R. §1.17(p).

b.  See the statement below. No fee is required.

VI.  **THIS IDS IS BEING FILED UNDER 37 C.F.R. §1.97(d):**

on or before payment of the issue fee and is accompanied by the following:

1) a statement under 37 C.F.R. §1.97(e) as provided below; and

2) charge deposit account 50-1047 the petition fee set forth in §1.17(p).

VII.  **STATEMENT UNDER 37 C.F.R. §1.97(e) (check only one box, if applicable)**

The undersigned hereby states that

a.  each item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application not more than three months prior to the filing of IDS; or

b.  no item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application, and to knowledge of the person signing the statement after making reasonable inquiry, no item of information contained in the IDS was known to any individual designated in 37 C.F.R. 1.56(c) more than three months prior to the filing of this statement, or

c.  some of the items of information contained in the IDS were cited in a communication from a foreign Patent Office. As to this information, the undersigned states that each item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application not more than three months prior to the filing of this IDS. As to the remaining information, the undersigned hereby states that no item of this remaining information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application or, to the knowledge of the person signing the statement after making reasonable inquiry, no item of information contained in the IDS was known to any individual designated in 37 C.F.R. 1.56(c) more than three months prior to the filing of this statement.

VIII. **PAYMENT OF FEES**

A check in the amount of \_\_\_\_\_ is enclosed for the above-identified fee(s).

Please charge Deposit Account No. 50-1047 in the amount of \$180.00 for the above-indicated fee(s).

If Applicant has overlooked any additional fees, or if any overpayment has been made, the Commissioner is hereby authorized to credit or debit Deposit Account 50-1047.

Two Copies of this paper are attached for Deposit Account charges and debits.

It is Applicant(s)' opinion that the claims presently on file patently distinguish the present invention from each of these references. The above references are being cited only in the interests of candor and without any admission that they constitute statutory prior art or contain matter which anticipates the invention or which would render the same obvious, either singly or in a combination, to a person of ordinary skill in the art.

If the Examiner has any questions concerning this IDS, he/she is requested to contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the PTO is requested to consider this IDS under the proper rule (with a petition if necessary) and charge the appropriate fee to Deposit Account No. 50-1047.

Respectfully submitted,  
Mayer Fortkort & Williams, PC

  
Karin L. Williams  
Attorney for Applicant  
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Mayer Fortkort & Williams, PC  
Customer Number 27774

Enclosures:  PTO/SB/08  
 References  
 Foreign Search Report  
 Other:

Certificate of Mailing By Express Mail

I hereby certify that this correspondence is being deposited with the United States Postal Service as "Express Mail Post Office to Addressee" service under 37 CFR 1.10 in an envelope addressed to: Mail Stop Patent, Commissioner for Patents, P. O. Box 1450, Alexandria, VA 22313-1450 on 9/29/03.

Marjorie Scariati  
(Printed name of Person Mailing Correspondence)

Marjorie Scariati  
(Signature)

**INFORMATION DISCLOSURE CITATION**  
(Use several sheets if necessary)

Docket Number (Optional)  
**D2337 D2**

Application Number  
**Unassigned**

Applicant(s)  
**Fwu-Iuan Hshieh et al.**

Filing Date

Filed Herewith

Group Art Unit

**2818**

**U.S. PATENT DOCUMENTS**

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	1	6,144,065	11/7/2000	Kinzer	257	327	
	2	6,025,237	2/15/2000	Choi	438	301	
	3	5,072,266	12/10/1991	Bulucea et al.	357	23.4	
	4	4,971,929	11/20/90	D'Anna et al.	437	192	
	5	5,770,514	06/23/1998	Matsuda et al.	438	589	
	6	5,567,634	10-1996	Hebert et al.	437	41	
	7	6,125,149	04-2001	Lee et al.	257	328	
	8	6,225,649	05-2001	Minato	257	133	
	9	5,541,425	07/30/1996	Nishihara	257	139	
	10	5,468,982	11/21/1995	Hshieh et al.	257	331	
	11	5,866,931	02/02/1999	Bulucea et al.	257	331	

**FOREIGN PATENT DOCUMENTS**

REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
1	WO 94/03922	02/17/1994	PCT	H01L 21	265	✓	
2	61190981	08/25/1986	JP	H01L 29	78		✓
3	DE 19507146A1	11/1/1996	Germany	H01L 29	78		✓

**OTHER DOCUMENTS** (Including Author, Title, Date, Pertinent Pages, Etc.)

1 Matsumoto, S. et al., "A 70-V, 90-mA/mm<sup>2</sup>, High-Speed Double-Layer Gate UMOSFET Realized by Selective CVD Tungsten, Proceedings of the 6th International Symposium on Power Semiconductor Devices & IC's, Switzerland, May 31-June 2, 1994, pgs. 365-369.

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.